Sig	gnature and Name of Invigilator		OMR She	eet N	o. :	•••••				
1.	(Signature)				(To	be fil	led by	the C	andi	date)
	(Name)		Roll No.							
2.	(Signature)			(Ir	ı figu	res as	per a	dmiss	ion c	ard)
	(Name)		Roll No							
	(trume)				(]	ln wo	ords)			
Ι)-8809		Test Book	klet l	No.					
Tir	ne : 1 ¹ / ₄ hours] PAPI	ER-	II			ſΜa	aximı	ım M	arks	: 100
	ELECTRON	IC	SCIENCE			[212		,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,		. 200
Νι	imber of Pages in this Booklet : 16		Numb		Oues	stions	s in th	nis Bo	okle	t : 50
_	Instructions for the Candidates						ए निर्देश			
 2. 3. 	Write your roll number in the space provided on the top of this page. This paper consists of fifty multiple-choice type of questions. At the commencement of examination, the question booklet will be given to you. In the first 5 minutes, you are requested to open the booklet and compulsorily examine it as below: (i) To have access to the Question Booklet, tear off the paper seal on the edge of this cover page. Do not accept a booklet	1. 2. 3.	पहले पृष्ठ के ऊपर रि इस प्रश्न-पत्र में पचा परीक्षा प्रारम्भ होने प् मिनट आपको प्रश्न- लिए दिये जायेंगे जिल् (i) प्रश्न-पुस्तिका सील को फाड़ स्वीकार न करें	नियत स् ास बहुि गर, प्रश्- -पुस्तिव सकी जें खोलने : लें । :	थान पर वकल्पी न-पुस्ति ज खोल ॉच आप के लिए	अपना य प्रश्न का आ वि तथा प्रको अ ए उसके	ा रोल न हैं। पको दे उसकी वश्य क	म्बर लि दी जायेग निम्नि रनी है : रेज पर त	गी । प नखित नगी क	हले पाँच जाँच के गगज की
	without sticker-seal and do not accept an open booklet. (ii) Tally the number of pages and number of questions in the booklet with the information printed on the cover page. Faulty booklets due to pages/questions missing or duplicate or not in serial order or any other discrepancy should be got replaced immediately by a correct booklet from the invigilator within the period of 5 minutes. Afterwards, neither the Question Booklet will be replaced nor any extra time will be given. (iii) After this verification is over, the Test Booklet Number should be entered in the OMR Sheet and the OMR Sheet		(ii) कवर पृष्ठ पर की संख्या को पुस्तिका जिनम् में न हों अर्थात करें तथा उसी प्रश्न-पुस्तिका उसके बाद न व ही आपको आं (iii) इस जाँच के ब अंकित करें औ अंकित कर दें	छपे नि अच्छी में पृष्ठ/! कसी समय ले लें । तो आप तिरिक्त प्रश्नाद प्रश्नाद OM	ा तरह प्रश्न क असे ल इसके वि की प्रश् । समय न-पुस्ति	चैक क म हों या कार की गैटाकर लेए आ न-पुस्ति विया ज का की	तर लें वि । दुबारा । त्रुटिपूर - उसके ।पको पाँ तका वार नायेगा - क्रम सं	क ये पूरे आ गये र्ण पुस्ति स्थान प् चि मिनव पस ली ख्या O	हों या हों या का स्व ार दूस टिंदये जायेर्ग MR	दोषपूर्ण सीरियल गेकार न रिी सही जायेंगे। अरेर न
4.	Number should be entered on this Test Booklet. Each item has four alternative responses marked (A), (B), (C) and (D). You have to darken the oval as indicated below on the correct response against each item. Example: A B D D where (C) is the correct response.	4.	प्रत्येक प्रश्न के लिए हैं। आपको सही उत्त कि नीचे दिखाया गय उदाहरण:	चार उत्त नर के र्द गा है ।						
5.	Your responses to the items are to be indicated in the Answer Sheet given inside the Paper I Booklet only. If you mark at any place other than in the ovals in the Answer Sheet, it will not be evaluated.	5.	जबिक (C) सही उत्त प्रश्नों के उत्तर केवल अंकित करने हैं। य किसी अन्य स्थान प होगा।	ग्रश्न दि आप	उत्तर प	पत्रक प	र दिये ग	गये दीर्घ	वृत्त के	अलावा
6.	Read instructions given inside carefully.	6.	अन्दर दिये गये निर्देश	शों को १	ध्यानपृष्	क पढ़ें	1			
	Rough Work is to be done in the end of this booklet. If you write your name or put any mark on any part of the test booklet, except for the space allotted for the relevant entries, which may disclose your identity, you will render yourself liable to disqualification.	7. 8.	कच्चा काम (Roug यदि आप उत्तर-पुस्ति आपकी पहचान हो र परीक्षा के लिये अयो	तका पर प्रके, वि एय घोरि	अंपना ज्सी भी षत कर	नाम य भाग प दिये ज	या ऐसा र दर्शाते गयेंगे ।	कोई भी या अंवि	निशान कत क	न जिससे रते हैं तो
9.	You have to return the test question booklet and OMR Answer sheet to the invigilators at the end of the examination compulsorily and must not carry it with you outside the Examination Hall.		आपको परीक्षा समा निरीक्षक महोदय को अपने साथ परीक्षा भ केवल नीले/काले ब	लौटान ावन से ाल प्वा	ा आवश बाहर न ईंट पैन	यक हैं । I लेकर का ही	और परी जायें । इस्तेमा	क्षा समा ल करें ।	प्ति के	बाद उसे
	Use only Blue/Black Ball point pen.	11.	किसी भी प्रकार क प्रयोग वर्जित है ।	ा संगण	ाक (कै	लकुले	टर) या	लाग टे	बल ३	गदि का
	Use of any calculator or log table etc., is prohibited. Negative Marking:- For each incorrect answer, 0.5 marks	12.	नेगेटिव अंक प्रणाल	र्गी : प्रत	येक गत	ात उत्त	र के लि	ए 0.5 इ	अंक क	ाटे
14.	shall be deducted.		जाएँगे।		,	,		,		-

ELECTRONIC SCIENCE

Paper – II

Note: This paper contains fifty (50) objective type questions, each question carrying two (2) marks. Attempt all the questions.

1.	Whic	Which diode exhibits negative resistance characteristics?											
	(A)	Zener	(B)	Tunnel									
	(C)	Schottky	(D)	PIN									
2.	Whic	ch crystal structure is preferred to	o fabrio	eate BJT in VLSI technology ?									
	(A)	<111>											
	(B)	<100>											
	(C)	<110>											
	(D)	None of the above											
3.	Network contains only independent current sources and resistors. If the values of the all resistors are doubled, the value of the node voltages will												
	(A)	become half											
	(B)	remain unchanged											
	(C)	become double											
	(D)	be undeterminate											
4.		V source is connected in serie th is closed at t = 0, the current in		a 1 Ω resistor and 1 H inductor and the it is									
	(A)	$10 + 10 e^{100 t}$	(B)	$10 - 10 e^{100 t}$									
	(C)	$10 + 10 e^{-100 t}$	(D)	$10 - 10 e^{-100 t}$									
5.	A dif	A differential amplifier is used at the input stage of an Op Amp to give very high											
	(A)	CMRR	(B)	Bandwidth									
	(C)	Slew rate	(D)	Open loop gain									

6.	What	What is the current sourcing capacity of 7805 IC voltage regulator?										
	(A)	0.5 Amp	(B)	2 Amp								
	(C)	1 Amp	(D)	5 Amp								
7.	Which is the fastest logic family?											
	(A)	TTL	(B)	CMOS								
	(C)	RTL	(D)	ECL								
8.	The minimum number of NAND gates to implement $A + A\overline{B} + A\overline{B}C$											
	(A)	Zero	(B)	1								
	(C)	4	(D)	5								
9.	In which T state of every machine cycle for 8085 does ALE signal become active ?											
	(A)	T2	(B)	T1								
	(C)	T3	(D)	T4								
10.	The bit addressable RAM area in 8051 microcontroller is											
	(A)	00 H – 1 F H	(B)	20 H – 2 F H								
	(C)	30 H – 3 F H	(D)	40 H – 4 F H								
11.	What is the storage space required for a character ?											
	(A)	1 byte	(B)	2 bytes								
	(C)	3 bytes	(D)	4 bytes								
12.	Which is an infinite loop in C language ?											
	(A)	for $(x = 0; x \le 10, x + +)$	(B)	for $(; x \ge 10)$								
	(C)	for $(x = 0; x \le 10)$	(D)	for $(;;x++)$								
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13.	The direction of propagation of EM wave is obtained from							
	(A)	$\overline{\mathbf{E}}\cdot\overline{\mathbf{H}}$	(B)	Ē				
	(C)	$\overline{E} \times \overline{H}$	(D)	Ħ				
14.	The l	ength of an antenna operating at	freque	ency 0.5 GHz is				
	(A)	570 m	(B)	5.70 m				
	(C)	57.0 m	(D)	600 m				
15.	A pre	e-emphasis circuit provides extra	noise	immunity by				
	(A)	boosting the bass frequencies.						
	(B)	amplifying the higher audio fre	quenc	cies.				
	(C)	pre-amplifying the whole audio	band					
	(D) converting the phase modulation to FM.							
16.	In or	der to separate channels in a TDM	iver, it is necessary to use					
	(A)	AND gates	(B)	band pass filters				
	(C)	differentiators	(D)	integrators				
17.	The o	capacitive current flowing through	h the j	unction of a thyristor is given by				
	(A)	$C \cdot \frac{dt}{dv}$	(B)	$\frac{1}{C}\frac{dv}{dt}$				
	(C)	$\frac{1}{C}\frac{dt}{dv}$	(D)	$C\frac{dv}{dt}$				
18.	A du	al converter is used in where						
(A) Reversible d.c. is required.								
	(B)	a.c. of higher frequency is requ	ired.					
	(C)	a.c. of low frequency is require						
	(D)	ripple free d.c. is required.						
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- **19.** Which is the static specification of a transducer?
 - (A) Rise time
 - (B) Settling time
 - (C) Hysteresis
 - (D) Frequency response
- **20.** In which mode the controller works as a variable gain amplifier?
 - (A) On-off
 - (B) Proportional
 - (C) Integral
 - (D) PID

Question 21 to 30:

The following items consist of two statements, one labelled as "Assertion (A)" and the other labelled as "Reason (R)". You are to examine these two statements carefully and decide if the Assertion (A) and the Reason (R) are individually true and if so, whether the reason is a correct explanation of the Assertion, select your answers to these items using the codes given below and mark your answer accordingly.

Codes:

- (A) Both (A) and (R) are true and (R) is the correct explanation of (A).
- (B) Both (A) and (R) are true but (R) is not correct explanation of (A).
- (C) (A) is true but (R) is false.
- (D) (A) is false but (R) is true.
- 21. Assertion (A): The temperature compensation circuits require additional hardware and add to the complexity, instead one zener diode sufficies the work.
 - **Reason (R)** : The temperature coefficient of 5 V zener diode is nearly zero.

- **22. Assertion (A):** The z-transforms study yields information on placement of poles and zeroes in s-plane.
 - **Reason (R)** : Poles on the real axis in left half of s-plane give exponentially decaying response.
- **23. Assertion** (A): Current 4-20 mA loop overcomes the problem of loop resistance leading to signal degradation.
 - **Reason (R)**: V to F convertor is preferred because it is not affected by loop resistance.
- **24. Assertion** (A) : NAND gate provides universality.
 - **Reason** (**R**) : The universality is possible by De-Morgan's theorem.
- **25. Assertion** (A): Queue system is not provided in 8086 microprocessor.
 - **Reason (R)**: Queue helps interfacing slow memory without speed degradation.
- **26. Assertion** (A): The memory addresses are manipulated in 'c' through pointers.
 - **Reason** (**R**) : Pointers in 'c' can be added.
- 27. Assertion (A): Ionosphere is used for the transmission of HF waves.
 - **Reason (R)** : They are reflected back by the D, E, F_1 and F_2 layers.
- **28. Assertion** (A) : Choppers are used for the speed control of d.c. drives.
 - **Reason (R)** : Cycloconverters may not be used for the control of d.c. drives.

29.		ertion son (F		Ray	Optical fiber provides the attenuation of the order of 0.2 dB/km. Layleigh scattering increases with the increase in the operating vavelength.							
30.	Asse	ertion	(A) :	: Telemetry is used for smart instrumentation in digital control systems in modern industrial units.								
	Reason (R) :				They are capable of measuring the parameters of a process at a distance.							
31.	See 1	the sta	iges in	IC Fa	abrication below							
	(i)	Etc	hing									
	(ii)	Cle	aning									
	(iii)	iii) Masking and exposure										
	(iv) Application of photo resist											
	Mention the correct sequence followed:											
	(A)	(i)	(ii)	(iii)	(iv)							
	(B)	(ii)	(iv)	(iii)	(i)							
	(C)	(i)	(iii)	(iv)	(ii)							
	(D)	(iv)	(iii)	(ii)	(i)							
32.	Cons	sider t	he inp	ut imj	pedance of the following:							
	(i)	ope	n loop	Op A	Amp							
	(ii)	(ii) BJT										
	(iii)	(iii) MOSFET										
	(iv) JFET											
	Which is the way of showing the decrease in input impedance?											
	(A)	(iv)	(i)	(ii)	(iii)							
	(B)	(iii)	(ii)	(i)	(iv)							
	(C)	(i)	(iii)	(iv)	(ii)							
	(D)	(ii)	(iv)	(i)	(iii)							

(i) CMOS (ii) TTL (iii) LS TTL (iv) ECL Write the sequence of power consumption in increasing order. (A) (iii) (i) (ii) (iv) (B) (ii) (iv) (i) (iii) (C) (iv) (iii) (ii) (i) (D) (i) (iii) (ii) (iv) 34. Consider the quantum efficiency of the detector in optical communication. (i) Photo diode (ii) Photo transistor (iii) APD (iv) PIN diode Write the quantum efficiency of the above devices in decreasing order. (A) (iii) (iv) (ii) (i) (B) (iv) (iii) (ii) (i) (C) (ii) (i) (iii) (iv) (D) (i) (ii) (iii) (iv) 35. Consider the following transducers. (i) Thermistor (ii) Thermocouple (iii) RTD (iv) IC sensor Write the linearity order of the above in increasing order. (A) (ii) (iii) (ii) (iv) (B) (i) (iii) (iii) (iv)	33.	Cons	sider t	he fol	lowing	g logic	families :			
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(A) (iii) (iv) (ii) (i) (B) (iv) (iii) (ii) (ii) (C) (ii) (i) (iii) (iv) (D) (i) (ii) (iii) (iv) 35. Consider the following transducers. (i) Thermistor (ii) Thermocouple (iii) RTD (iv) IC sensor Write the linearity order of the above in increasing order. (A) (ii) (iii) (i) (iv)		(iii)	AP	D			(i	v)	PIN diode	
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35. Consider the following transducers. (i) Thermistor (ii) Thermocouple (iii) RTD (iv) IC sensor Write the linearity order of the above in increasing order. (A) (ii) (iii) (i) (iv)		(C)	(ii)	(i)	(iii)	(iv)				
 (i) Thermistor (ii) Thermocouple (iii) RTD (iv) IC sensor Write the linearity order of the above in increasing order. (A) (ii) (iii) (i) (iv) 		(D)	(i)	(ii)	(iii)	(iv)				
 (i) Thermistor (ii) Thermocouple (iii) RTD (iv) IC sensor Write the linearity order of the above in increasing order. (A) (ii) (iii) (i) (iv) 										
(iii) RTD (iv) IC sensorWrite the linearity order of the above in increasing order.(A) (ii) (iii) (i) (iv)	<i>3</i> 5.					g trans		• `	TTI 1	
Write the linearity order of the above in increasing order. (A) (ii) (iii) (i) (iv)					or				-	
(A) (ii) (iii) (i) (iv)		, ,			. 1	C 41				
					•		ne above in i	ncre	easing order.	
(B) (1) (11) (111) (1V)										
(C) (iv) (iii) (ii) (i)										
(D) (iii) (i) (iv) Paper-II 8 D-8800			(111)	(11)	(1)	(1V)				

36. Match List-I with List-II, and select the correct answers using the codes given below the lists: List-I List-II **SCR** Relaxation oscillator (a) (i) (b) Zener diode (ii) Voltage variable resistor (c) UJT (iii) Voltage regulator (d) FET Controlled Rectifier (iv) **Codes:** (b) (d) (a) (c) (A) (ii) (i) (iii) (iv) (B) (ii) (i) (iii) (iv) (C) (iii) (ii) (i) (iv) (D) (iv) (iii) (i) (ii) **37.** Match List-I with List-II and select the correct answers using the codes given below the lists: List-I List-II Bode plot (i) (a) Current source Transient analysis (ii) Frequency domain (b) Norton's theorem (iii) Stability analysis Fourier's Transform (iv) Laplace transform **Codes:** (a) (b) (d) (c) (A) (iv) (iii) (i) (ii) (B) (iii) (iv) (ii) (i) (C) (iii) (ii) (i) (iv) (D) (i) (iv) (ii) (iii)

38. Match List-I with List-II and select the correct answers using the codes given below the lists: List-I List-II (a) IC-723 (i) Lock-range Oscillators 25 mA (ii) (c) IC-741 (iii) Voltage regulator (d) PLL Positive feedback (iv) **Codes:** (a) (b) (c) (d) (A) (iii) (iv) (ii) (i) (B) (ii) (iii) (iv) (i) (C) (i) (ii) (iii) (iv) (D) (iv) (ii) (iii) (i) **39.** Match List-I with List-II and select the correct answers using the codes given below the lists: List-I List-II Digital Multimeters (a) Flip flop (i) (b) Counters (ii) Memory Data acquisition systems (c) **XOR-gates** (iii) (d) D to A convertor (iv) Parity checkers **Codes:** (a) (b) (d) (c) (A) (iii) (ii) (iv) (i) (B) (iv) (ii) (i) (iii) (C) (ii) (i) (iv) (iii) (D) (i) (ii) (iii) (iv)

40. Match List-I with List-II and select the correct answers using the codes given below the lists: List-I List-II (a) 8085 (i) On chip timer (b) 8086 Serial I/O pins (ii) (c) 8255 (iii) Segmented memory (d) 8051 Hand-shake mode (iv) **Codes:** (a) (b) (c) (d) (A) (i) (ii) (iii) (iv) (B) (iv) (iii) (ii) (i) (C) (iii) (ii) (i) (iv) (D) (ii) (iii) (iv) (i) 41. Match List-I with List-II and select the correct answers using the codes given below the lists: List-I List-II Character storage space (i) \r (b) O/p Array of characters (ii) while (1) (c) Infinite Loop 1-byte (iii) (d) bring cursor to the (iv) % S beginning of current line **Codes:** (a) (b) (c) (d) (A) (iii) (iv) (ii) (i) (B) (i) (ii) (iii) (iv) (C) (iv) (iii) (ii) (i) (D) (ii) (iii) (i) (iv)

42. Match List-I with List-II and select the correct answers using the codes given below the lists: List-I List-II (a) **EDFA** (i) Ability to collect the light **Optical Amplifiers** (b) LASER (ii) (c) Numerical Aperture (iii) Spontaneous Emission (d) LED (iv) Stimulated Emission **Codes:** (d) (a) (b) (c) (A) (iii) (ii) (iv) (i) (B) (ii) (iv) (iii) (i) (C) (iv) (ii) (i) (iii) (D) (iii) (ii) (iv) (i) **43.** Match List-I with List-II and select the correct answers using the codes given below the lists: List-I List-II (a) FM (i) Microwave generator Ratio detector (b) AM (ii) Quantization (iii) PCM (d) Magnetron (iv) Envelope detector **Codes:** (d) (a) (b) (c) (A) (i) (ii) (iii) (iv) (B) (iv) (ii) (iii) (i) (C) (i) (ii) (iii) (iv) (D) (ii) (iv) (iii) (i)

44. Match List-I with List-II and select the correct answers using the codes given below the lists: List-I List-II (a) **RTD** (i) Infinite Resolution Hall Effect (ii) Change of Resistance **Instrumentation Amplifier** (iii) Magneto resistance (d) LVDT High end variable gain (iv) **Codes:** (a) (b) (c) (d) (A) (i) (ii) (iii) (iv) (B) (iv) (iii) (ii) (i) (C) (ii) (iii) (iv) (i) (D) (i) (iv) (iii) (ii) 45. Match List-I with List-II and select the correct answers using the codes given below the lists: List-I List-II On-off control (i) Stability Proportional control (b) (ii) Dead zone (c) PID Residual error (iii) Zero offset error (d) Routh-Hurwitz (iv) **Codes:** (a) (b) (d) (c) (A) (iv) (iii) (ii) (i) (B) (iv) (ii) (iii) (i) (C) (iii) (ii) (iv) (i) (D) (ii) (iii) (iv) (i)

Read the passage below, answer the questions from 46 to 50, that follow based on your understanding of the passage.

Frequency modulation (FM) and phase modulation (PM) are two forms of angle modulation which is a form of continuous wave or analog modulation whose chief characteristics are as follows:

- (1) The amplitude of the modulated carrier is kept constant.
- (2) The frequency of the modulated carrier is varied by the modulating voltage.

In frequency modulation the carrier's frequency deviation is proportional to the instantaneous amplitude of the modulating voltage. In phase modulation, the carrier's phase deviation is proportional to the instantaneous amplitude of the modulating voltage. It has been mathematically shown that as the modulating frequency decreases and the modulating voltage amplitude remains constant the modulation index increases. The modulation index determines how many side bands have significant amplitude. The major advantages of angle modulation over amplitude modulation are

- (1) The transmitted amplitude is constant and thus the receiver can be fitted with an efficient amplitude limiter; this characteristics has the advantage of improving immunity to noise and interference.
- (2) Since there is no natural limit to the modulation index, it can be increased to provide additional noise immunity.

The noise-signal distribution is rectangular in AM and PM, whereas triangle in FM. To reduce the effect of noise wideband FM is used for broadcast transmissions for the sound accompanying TV transmissions. Narrow band FM is used for communications in competition with single side band having its main applications in various forms of mobile communications.

The reactance modulator is a direct method of generating FM. The alternative means of generating FM the Armstrong system is one of which PM is initially generated but the modulating frequencies are correctly bass-boosted; thus FM results in output. A very small frequency deviations are possible in basic Armstrong system.

- **46.** In the spectrum of frequency modulated wave
 - (A) the carrier frequency disappears when the modulation index is large.
 - (B) the amplitude of any sideband depends on the modulation index.
 - (C) the total number of sideband depends on the modulation index.
 - (D) the carrier frequency cannot disappear.

- **47.** The difference between phase and frequency modulation
 - (A) is purely theoretical because they are the same in practice.
 - (B) is too great to make the two system compatible.
 - (C) lies in the different definitions of the modulation index.
 - (D) lies in the poorer audio response of phase modulation.
- **48.** Indicate the false statement regarding the Armstrong modulation system.
 - (A) The system is basically phase modulation not FM.
 - (B) Automatic frequency control is not needed as a crystal oscillator is used.
 - (C) FM must be used.
 - (D) Equalization is unnecessary.
- **49.** Since noise-phase modulates the FM wave as the noise sideband frequency approaches the carrier frequency, the noise amplitude
 - (A) remains constant
 - (B) is decreased
 - (C) is increased
 - (D) is equalized
- **50.** Indicate which one of the following is not an advantage of FM and Amplitude Modulation?
 - (A) Better noise immunity is provided
 - (B) Lower Bandwidth is required.
 - (C) The transmitted power is more useful.
 - (D) Less modulating power is required.

Space for Rough Work